# imall

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## **General Description**

The MAX3250 is a 3.0V to 5.5V powered,  $\pm$ 50V isolated EIA/TIA-232 and V.28/V.24 communications interface with high data-rate capabilities. The MAX3250 is a dual die part that operates with up to  $\pm$ 50V difference between the RS-232 side and the logic side (ISOCOM to GND). This makes the device ideal for operation in noisy conditions with high common-mode voltages. This feature prevents damage to the device if RS-232 lines are inadvertently short-circuited to a +24V or  $\pm$ 48V power bus.

The MAX3250 is powered by a single 3V to 5.5V supply on the logic side. Power is transferred from the logic side to the isolated side by  $\pm 100V$  external capacitors.

The MAX3250 has two receivers (Rx) and two drivers (Tx) and is guaranteed to run at data rates of 250kbps while maintaining RS-232 output levels. The transceivers have a proprietary low-dropout transmitter output stage, delivering true RS-232 performance from a 3V to 5.5V supply with a dual charge pump. The device features a FAULT open-drain output to signal an excessive isolated-side voltage condition on any of the RS-232 inputs. This output can drive an alarm LED or can be monitored by the processor to prevent operation under these conditions. The receiver outputs are high impedance in shutdown, allowing multiple interfaces (IrDA, RS-232, RS-485) to be connected to the same UART.

The MAX3250 is available in a space-saving 28-pin SSOP package.

## Applications

Industrial Control

Programmable Logic Controller

Typical Operating Circuit appears at end of data sheet.

- Point-of-Sale Equipment
- PC-to-Router Connections
- **Diagnostic Ports**
- **Telecom Equipment**

## \_\_\_\_\_Features

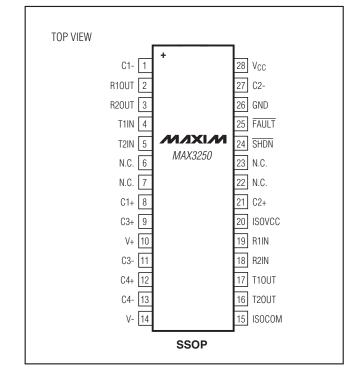
- ±50V Isolation
- 20µA Supply Current in Shutdown
- ♦ 250kbps Guaranteed Data Rate
- ♦ FAULT Output
- High-Impedance Transmitter and Receiver Outputs in Shutdown
- Space-Saving SSOP Package
- Inductorless/Transformerless Design Simplifies EMI Compliance
- Low-Cost Replacement for Opto-Isolated Transceivers
- ♦ Meets EIA/TIA-232 Specifications Down to 3.0V

## **Ordering Information**

| 0°C 28 SSOP |
|-------------|
| 5°C 28 SSOP |
|             |

+Denotes a lead(Pb)-free/RoHS-compliant package.

## **Pin Configuration**



#### 

\_ Maxim Integrated Products 1

For pricing delivery, and ordering information please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

## **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to GND, unless otherwise noted.)

| () in voltagee relevenced to arte, and |                                  |
|----------------------------------------|----------------------------------|
| V <sub>CC</sub>                        |                                  |
| ISOCOM                                 | ±80V                             |
| ISOVCC to ISOCOM                       | 0.3V to +6V                      |
| V+ to ISOCOM (Note 1)                  | 0.3V to +7V                      |
| V- to ISOCOM (Note 1)                  | +0.3V to -7V                     |
| V+ + IV-I (Note 1)                     | 13V                              |
| Input Voltages                         |                                  |
| T_IN, <u>SHDN</u>                      | 0.3V to +6V                      |
| R_IN to ISOCOM                         | ±25V                             |
| Output Voltages                        |                                  |
| T_OUT to ISOCOM                        |                                  |
| R_OUT                                  | 0.3V to (V <sub>CC</sub> + 0.3V) |
| FAULT                                  |                                  |
| C1-, C2                                | 0.3V to (V <sub>CC</sub> + 0.3V) |
|                                        |                                  |

| C1+, C2+, C3+, C3-, C4+, C4-                          |
|-------------------------------------------------------|
| to ISOCOM0.3V to (ISOVCC + 0.3V)                      |
| T_OUT Current                                         |
| R_IN Current                                          |
| ISOCOM Current                                        |
| Short-Circuit Duration T_OUT to ISOCOMContinuous      |
| Continuous Power Dissipation ( $T_A = +70^{\circ}C$ ) |
| 28-Pin SSOP (derate 15mW/°C above +70°C) 1201.2mW     |
| Operating Temperature Ranges                          |
| MAX3250CAI0°C to +70°C                                |
| MAX3250EAI40°C to +85°C                               |
| Storage Temperature Range65°C to +150°C               |
| Lead Temperature (soldering, 10s)+300°C               |
| Soldering Temperature (reflow)+260°C                  |

Note 1: V+ and V- can have a maximum magnitude of 7V, but their absolute difference cannot exceed 13V.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

(V<sub>CC</sub> = 3.0V to 5.5V, see Typical Operating Circuit and Table 1 for capacitor values, ISOCOM = GND,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at V<sub>CC</sub> = 3.3V and  $T_A = +25^{\circ}$ C.) (Note 2)

| PARAMETER                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |                                            | CONDITIONS                                  | MIN | ТҮР                   | MAX  | UNITS    |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|---------------------------------------------|-----|-----------------------|------|----------|
| DC CHARACTERISTICS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |                                            |                                             |     |                       |      | •        |
| Supply Current                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | $\overline{\text{SHDN}} = V_{CC}$ , no los | $\overline{\text{SHDN}} = V_{CC}$ , no load |     | 15                    | 35   | mA       |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | SHDN = GND, VISO                           | COM = GND                                   |     | 20                    | 45   | <u>,</u> |
| Supply Current Shutdown                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | SHDN = GND, VISO                           | $COM = \pm 50V$                             |     |                       | ±350 | μA       |
| Maximum Ground Differential                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         | VGND - VISOCOM                             |                                             |     |                       | 50   | V        |
| Isolation Resistance                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Between GND and                            | ISOCOM                                      |     | 60                    |      | kΩ       |
| LOGIC INPUTS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |                                            |                                             |     |                       |      |          |
| Input Logic Low                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | T_IN, SHDN                                 |                                             |     |                       | 0.8  | V        |
| la sectional de la companya de |                                            | $V_{CC} = 3.3V$                             | 2.0 |                       |      | V        |
| Input Logic High                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | T_IN, SHDN                                 | $V_{CC} = 5.0V$                             | 2.4 |                       |      | V        |
| Transmitter Input Hysteresis                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |                                            |                                             |     | 0.5                   |      | V        |
| Input Leakage Current                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | T_IN, SHDN                                 | T_IN, SHDN                                  |     | ±0.01                 | +1   | μA       |
| RECEIVER OUTPUTS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | •                                          |                                             | ·   |                       |      |          |
| Output Leakage Current                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | SHDN = GND                                 | SHDN = GND                                  |     | ±0.05                 | +10  | μA       |
| Output-Voltage Low                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  | $I_{OUT} = 1.6 \text{mA}$                  |                                             |     |                       | 0.4  | V        |
| Output-Voltage High                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | I <sub>OUT</sub> = -1.0mA                  | I <sub>OUT</sub> = -1.0mA                   |     | 6 V <sub>CC</sub> - ( | 0.1  | V        |
| FAULT OUTPUT                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |                                            |                                             |     |                       |      |          |
| Output-Voltage Low<br>(Open Drain)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  | I <sub>OUT</sub> = 5mA                     |                                             |     |                       | 0.4  | V        |
| Output Leakage Current                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | FAULT not asserted                         |                                             |     |                       | 1    | μA       |
| FAULT Trip Level                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | VGND - VISOCOM                             |                                             |     | 55                    |      | V        |

## **ELECTRICAL CHARACTERISTICS (continued)**

(V<sub>CC</sub> = 3.0V to 5.5V, see Typical Operating Circuit and Table 1 for capacitor values, ISOCOM = GND,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at V<sub>CC</sub> = 3.3V and  $T_A = +25^{\circ}$ C.) (Note 2)

| PARAMETER                    | CC                                                    | CONDITIONS                                                                          |     | ТҮР  | MAX | UNITS |
|------------------------------|-------------------------------------------------------|-------------------------------------------------------------------------------------|-----|------|-----|-------|
| RECEIVER INPUTS (relative to | ISOCOM)                                               |                                                                                     | •   |      |     | •     |
| Input-Voltage Range          |                                                       |                                                                                     | -25 |      | +25 | V     |
| Input Throshold Low          |                                                       | $V_{CC} = 3.3V$                                                                     |     | 1.2  | 0.6 | V     |
| Input Threshold Low          | ut Threshold Low $T_A = +25^{\circ}C$ $V_{CC} = 5.0V$ |                                                                                     |     | 1.3  | 0.8 | v     |
| Input Thrashold High         |                                                       | $V_{CC} = 3.3V$                                                                     | 2.4 | 1.6  |     | V     |
|                              | $V_{CC} = 5.0V$                                       | 2.4                                                                                 | 1.7 |      | v   |       |
| Input Hysteresis             |                                                       |                                                                                     |     | 0.5  |     | V     |
| Input Resistance             | T <sub>A</sub> = +25°C                                | T <sub>A</sub> = +25°C                                                              |     | 5    | 7   | kΩ    |
| TRANSMITTER OUTPUTS (rel     | ative to ISOCOM)                                      |                                                                                     |     |      |     |       |
| Output-Voltage Swing         | All transmitter outputs los $T_A = +25^{\circ}C$      | All transmitter outputs loaded with $3k\Omega$ to ISOCOM,<br>T <sub>A</sub> = +25°C |     | ±5.4 |     | V     |
| Output Resistance            | ISOVCC = V + = V - = 0V                               | $ISOVCC = V + = V - = 0V, V_{T_OUT} = \pm 2V$                                       |     | 10M  |     | Ω     |
| Output Short-Circuit Current |                                                       |                                                                                     |     |      | +60 | mA    |
| Output Leakage Current       | V <sub>CC</sub> = 0 or 3V to 5.5V, V                  | $T_{OUT} = \pm 12V, \overline{SHDN} = GND$                                          | -25 |      | +25 | μA    |

## TIMING CHARACTERISTICS

(V<sub>CC</sub> = 3.0V to 5.5V, see Typical Operating Circuit and Table 1 for capacitor values, ISOCOM = GND,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at V<sub>CC</sub> = 3.3V and  $T_A = +25^{\circ}$ C.)

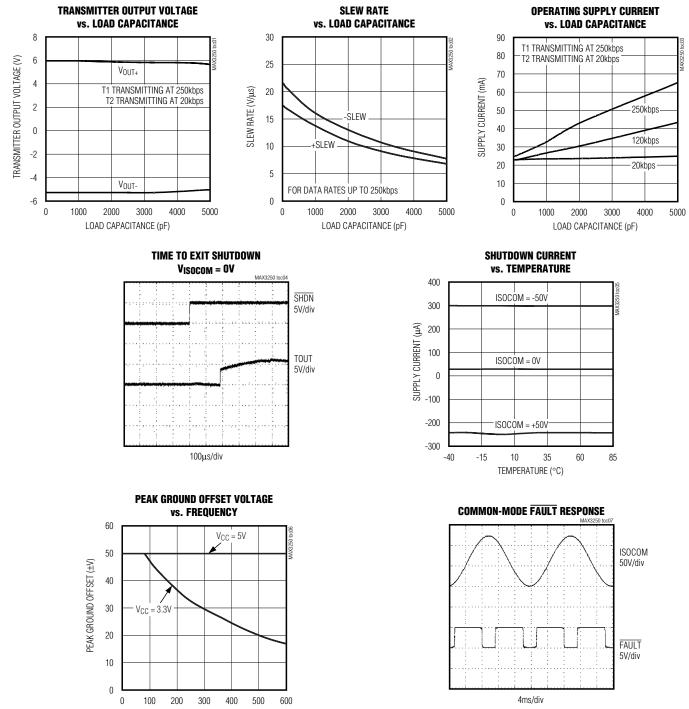
| PARAMETER                    | CONDIT                                                                                                      | CONDITIONS                                                                    |   |     | MAX | UNITS |
|------------------------------|-------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------|---|-----|-----|-------|
| Maximum Data Rate            | $ \begin{array}{l} R_{L} = 3 k \Omega,  C_{L} = 1000 pF \text{ to ISO} \\ T_{A} = +25^\circ C \end{array} $ | $R_L$ = 3k $\Omega,$ $C_L$ = 1000pF to ISOCOM, one transmitter, $T_A$ = +25°C |   |     |     | kbps  |
| Receiver Propagation Delay   | R_IN to R_OUT, $C_L = 150 pF$ to                                                                            | GND                                                                           |   | 0.4 |     | μs    |
| Receiver Skew                | tphl - tplh                                                                                                 |                                                                               |   | 100 |     | ns    |
| Transmitter Skew             | tphL - tpLH  (Note 3)                                                                                       | tpHL - tpLH  (Note 3)                                                         |   | 120 |     | ns    |
| Liransition-Region Slew Rate | $V_{CC} = 3.3V$ , $T_A = +25^{\circ}C$ ,<br>$R_L = 3k\Omega$ to $7k\Omega$ to ISOCOM,                       | C <sub>L</sub> = 150pF to 1000pF<br>to ISOCOM                                 | 6 |     | 30  | V/µs  |
|                              | measured from +3V to -3V or<br>-3V to +3V                                                                   | C <sub>L</sub> = 150pF to 2500pF<br>to ISOCOM                                 | 4 |     | 30  | v/µs  |
| FAULT Propagation Delay      |                                                                                                             |                                                                               |   | 0.3 |     | μs    |
| Time to Shutdown             |                                                                                                             |                                                                               |   | 0.5 |     | μs    |
|                              | V <sub>ISOCOM</sub> = GND                                                                                   | VISOCOM = GND                                                                 |   | 300 |     |       |
| Time to Exit Shutdown        | $V_{\rm ISOCOM} = \pm 50V$                                                                                  |                                                                               |   | 350 |     | μs    |

Note 2: All currents into the device are positive; all currents out of the device are negative. All voltages are referenced to device ground, unless otherwise noted.

Note 3: Transmitter skew is measured at the transmitter zero crosspoints.

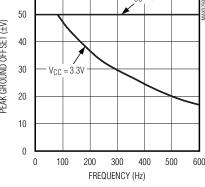


(V<sub>CC</sub> = 3.3V, 250kbps data rate, see Typical Operating Circuit and Table 1 for capacitor values, all transmitters loaded with  $3k\Omega$  and  $C_L$  to ISOCOM,  $T_A = +25^{\circ}C$ , unless otherwise noted.)



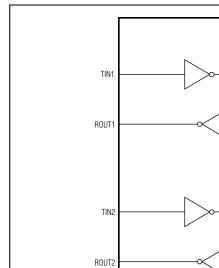


**MAX3250** 



## **Pin Description**

| PIN       | NAME   | FUNCTION                                                                                                                                                         |
|-----------|--------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1         | C1-    | Negative Terminal of the Power Isolation Capacitor. Connect a 100V capacitor from C1- to C1+. See Table 1 for values.                                            |
| 2         | R10UT  | TTL/CMOS Receiver Output                                                                                                                                         |
| 3         | R2OUT  | TTL/CMOS Receiver Output                                                                                                                                         |
| 4         | T1IN   | TTL/CMOS Transmitter Input                                                                                                                                       |
| 5         | T2IN   | TTL/CMOS Transmitter Input                                                                                                                                       |
| 6, 22, 23 | N.C.   | No Connection. Not internally connected.                                                                                                                         |
| 7         | N.C.   | No Connection. Leave unconnected or connect to ISOCOM.                                                                                                           |
| 8         | C1+    | Positive Terminal of the Power Isolation Capacitor. Connect a 100V capacitor from C1+ to C1 See Table 1 for values.                                              |
| 9         | C3+    | Positive Terminal of the Voltage-Doubler Charge-Pump Capacitor. Connect a 0.1µF capacitor from C3+ to C3                                                         |
| 10        | V+     | +5.5V Generated by the Charge Pump, Referenced to ISOCOM. Bypass V+ to ISOCOM with a $0.47\mu$ F capacitor.                                                      |
| 11        | C3-    | Negative Terminal of the Voltage-Doubler Charge-Pump Capacitor. Connect a 0.1µF capacitor from C3- to C3+.                                                       |
| 12        | C4+    | Positive Terminal of the Inverting Charge-Pump Capacitor. Connect a 0.47µF capacitor from C4+ to C4                                                              |
| 13        | C4-    | Negative Terminal of the Inverting Charge-Pump Capacitor. Connect a 0.47µF capacitor from C4- to C4+.                                                            |
| 14        | V-     | -5.5V Generated by the Charge Pump, Referenced to ISOCOM. Bypass V- to ISOCOM with a 0.47 $\mu F$ capacitor.                                                     |
| 15        | ISOCOM | Isolated Ground                                                                                                                                                  |
| 16        | T2OUT  | RS-232 Transmitter Output                                                                                                                                        |
| 17        | T1OUT  | RS-232 Transmitter Output                                                                                                                                        |
| 18        | R2IN   | RS-232 Receiver Input                                                                                                                                            |
| 19        | R1IN   | RS-232 Receiver Input                                                                                                                                            |
| 20        | ISOVCC | Internally Generated Isolated Power-Supply Voltage, Referenced to ISOCOM. Bypass ISOVCC to ISOCOM with a 2.2µF capacitor.                                        |
| 21        | C2+    | Positive Terminal of the Power Isolation Capacitor. Connect a 100V capacitor from C2+ to C2 See Table 1 for values.                                              |
| 24        | SHDN   | Shutdown Control. Drive $\overline{SHDN}$ low to enter low-power shutdown mode. Drive $\overline{SHDN}$ high or connect to V <sub>CC</sub> for normal operation. |
| 25        | FAULT  | Overvoltage Indicator. Active low, open drain.                                                                                                                   |
| 26        | GND    | Ground                                                                                                                                                           |
| 27        | C2-    | Negative Terminal of the Power Isolation Capacitor. Connect a 100V capacitor from C2- to C2+. See Table 1 for values.                                            |
| 28        | Vcc    | 3.0V to 5.5V Supply Voltage. Bypass $V_{CC}$ to GND with a 1µF capacitor.                                                                                        |



**MAX3250** 

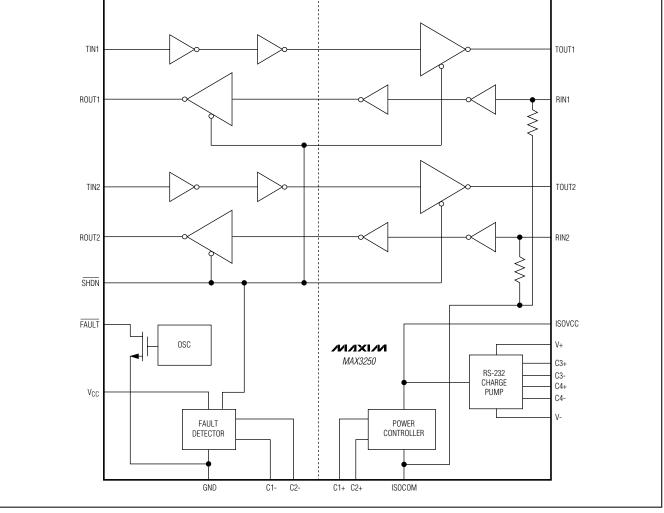


Figure 1. Functional Diagram

## **Detailed Description**

The MAX3250 is a 3.0V to 5.5V powered, ±50V isolated EIA/TIA-232 and V.28/V.24 communications interface with high data-rate capabilities. The MAX3250 is a dual die part that operates with up to ±50V difference between the RS-232 side and the logic side (ISOCOM to GND). This makes the device ideal for operation in noisy conditions with high common-mode voltages. This feature prevents damage to the device if RS-232 lines are inadvertently short-circuited to a +24V or ±48V power bus.

The MAX3250 typically draws 15mA of supply current when unloaded. Supply current drops to 20µA when the device is placed in shutdown mode.

The MAX3250 has two receivers and two drivers and is guaranteed to operate at data rates up to 250kbps. The device features a FAULT open-drain output to signal an excessive isolated-side voltage condition on any of the RS-232 inputs. This output can drive an alarm LED or can be monitored by the processor to prevent operation under these conditions. The receiver outputs are high impedance in shutdown, allowing multiple interfaces (IrDA, RS-232, RS-485) to be connected to the same UART (Figure 1). The MAX3250 is a low-cost replacement for opto-isolated transceivers.

#### **Isolated Power Supply**

The MAX3250 drives a high-frequency square wave into C1 and a complementary square wave into C2. These



AC waveforms are rectified on the isolated side of the dual die to power its internal circuitry (ISOVCC). Capacitor C6 filters the output of the rectifier. See the *Typical Operating Circuit*.

The power controller works in a dual power mode. Power is maximum when the isolated power supply is below its regulation point. Power is reduced when the isolated power supply is above its regulation point.

#### **Dual Charge-Pump Voltage Converter**

The RS-232 drivers are powered from a regulated dual charge pump that provides output voltages of +5.5V (doubling charge pump) and -5.5V (inverting charge pump) relative to ISOCOM over the 3.0V to 5.5V V<sub>CC</sub> range.

The charge pumps are powered from ISOVCC and operate in a discontinuous mode. If the output voltages are less than 5.5V, the charge pumps are enabled. If the output voltages exceed 5.5V, the charge pumps are disabled. Each charge pump requires a flying capacitor (C3, C4) and a reservoir capacitor (C7, C8) to generate the V+ and V- supplies.

#### **RS-232 Transmitters**

The transmitters are inverting level translators that convert TTL/CMOS-logic levels to  $\pm 5.0V$  EIA/TIA-232-compliant levels. They guarantee a 250kbps data rate with worst-case loads of  $3k\Omega$  in parallel with 1000pF to ISOCOM. In shutdown, the transmitters are disabled and the outputs are forced into a high-impedance state. When powered off or shut down, the outputs can be driven up to  $\pm 12V$  relative to ISOCOM. The transmitter inputs do not have pullup resistors. All unused inputs should be connected to V<sub>CC</sub> or GND.

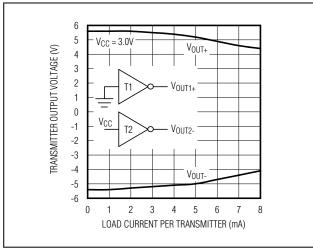


Figure 2. Transmitter Output Voltage vs. Load Current per Transmitter

**RS-232 Receivers** 

The receivers convert RS-232 signals to CMOS-logic output levels. The receivers' outputs are forced into a high-impedance state when the device is in shutdown. This allows a single UART to multiplex between different protocols.

#### Low-Power Shutdown Mode

Shutdown mode is obtained by driving SHDN low. In shutdown, the devices typically draw only 20µA of supply current and no power is transferred across the isolation capacitors. The charge pumps are disabled, and the receiver outputs and transmitter outputs are high impedance. When exiting shutdown the charge pumps and transmitter outputs are fully operational in typically 500µs (Figure 3). Connect SHDN to V<sub>CC</sub> if the shutdown mode is not used.

#### Applications Information

#### **Power Isolation Capacitors**

The values for capacitors C1 and C2 are important for proper operation of the device. These capacitors should be  $0.047\mu$ F for 4.5V to 5.5V operation, and  $0.47\mu$ F for 3.0V to 3.6V operation. Smaller values result in insufficient supply voltage on the isolated side. Larger values are not allowed.

Capacitor C9 provides an AC feedback path for proper controller operation. Connect C9 from ISOCOM to GND.

The values for C1, C2, and C9 determine the maximum frequency and amplitude of the voltage difference between the local and isolated ground. Table 1 shows proper capacitance values.

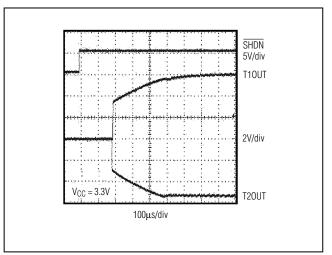


Figure 3. Transmitter Outputs when Exiting Shutdown or Powering Up

# **MAX3250**

### **Table 1. Required Capacitor Values**

| V <sub>CC</sub> (V) | C1, C2 (µF) | C3 (µF) | C4, C7, C8 (μF) | C5 (µF) | C6 (µF) | C9 (nF) |
|---------------------|-------------|---------|-----------------|---------|---------|---------|
| 3.0 to 3.6          | 0.47        | 0.1     | 0.47            | 1       | 2.2     | 10      |
| 4.5 to 5.5          | 0.047       | 0.1     | 0.47            | 1       | 2.2     | 10      |

To achieve full isolation capability, C1, C2, and C9 should be rated for 100V or higher operation and be X7R or X5R type or metalized film dielectric. Y5V and Z5U dielectrics should be avoided as their voltage and temperature coefficients make their power-transfer capabilities insufficient.

#### **Charge-Pump and Bypass Capacitors**

Capacitors C3–C8 should be X7R or X5R type dielectric. Their voltage rating needs to be 10V or higher.

#### Layout Information

Because the MAX3250 is intended for systems requiring  $\pm 50V$  isolation, some consideration in component placement is necessary.

A 20mil air gap should isolate the logic side and the isolated RS-232 side, across the N.C. pins (pin numbers 6, 7, 22, and 23) of the MAX3250. The only components that cross this air gap should be C1, C2, and C9, which should all have a minimum 100V rating.

All capacitors should be located as close to the MAX3250 as possible.

#### Maximum Voltage Between ISOCOM and Logic GND

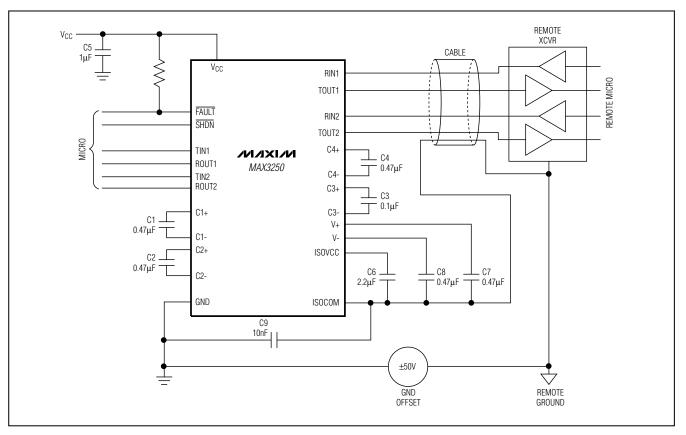
High values of applied isolation voltage and frequency can cause ripple on ISOVCC, V+, V-, and in extreme cases on V<sub>CC</sub>. Therefore, it is recommended that the isolation-voltage and frequency be limited to the values shown in the *Typical Operating Characteristics*.

Insert a  $1k\Omega$  1/4W resistor in series with any isolation test voltage when testing for maximum values of applied isolation voltage. Exceeding the maximum limits of voltage and frequency (see the *Typical Operating Characteristics*) could trigger a holding current in the internal ESD-protection device if the ±80V isolation limit is exceeded. This resistor should not be used in normal application.

#### Transmitter Outputs when Exiting Shutdown

Figure 3 shows two transmitter outputs when exiting shutdown mode. As they become active, the two transmitter outputs are shown going to opposite RS-232 levels (one transmitter input is high, the other is low). Each transmitter is loaded with  $3k\Omega$  in parallel with 2500pF. The transmitter outputs display no ringing or undesirable transients as they come out of shutdown. Note that the transmitters are enabled only when the magnitude of V- exceeds approximately -3V.

## **Typical Operating Circuit**



## **Chip Information**

PROCESS: BICMOS

## **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maxim-ic.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE | PACKAGE | OUTLINE        | LAND           |
|---------|---------|----------------|----------------|
| TYPE    | CODE    | NO.            | PATTERN NO.    |
| 28 SSOP | A28M+3  | <u>21-0056</u> | <u>90-0095</u> |

**MAX3250** 

| <br>Historv |
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| REVISION<br>NUMBER | REVISION<br>DATE | DESCRIPTION                                                                                                                                                                           | PAGES<br>CHANGED |
|--------------------|------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|
| 0                  | 4/02             | Initial release                                                                                                                                                                       | _                |
| 1                  | 2/03             | Updated Design                                                                                                                                                                        | —                |
| 2                  | 1/08             | Updated EC table                                                                                                                                                                      | 3                |
| 3                  | 9/11             | Added lead-free packaging information; corrected pin names, power dissipation, and soldering temperature in <i>Absolute Maximum Ratings</i> ; updated capacitor values in data sheet. | 1, 2, 3, 5–9     |

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.

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